













# 6-Pin DIP Optoisolators Darlington Output (Low Input Current)

The H11B1 and H11B3 devices consist of a gallium arsenide infrared emitting diode optically coupled to a monolithic silicon photodarlington detector. They are designed for use in applications requiring high output current ( $I_C$ ) at low LED input currents ( $I_F$ ).

- High Sensitivity to Low Input Drive Current (I<sub>F</sub> = 1 mA)
- To order devices that are tested and marked per VDE 0884 requirements, the suffix "V" must be included at end of part number. VDE 0884 is a test option.

#### **Applications**

- · Appliances, Measuring Instruments
- I/O Interfaces for Computers
- Programmable Controllers
- Interfacing and coupling systems of different potentials and impedances
- · Solid State Relays
- Portable Electronics

#### MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
INPUT LED			
Reverse Voltage	٧R	3	Volts
Forward Current — Continuous	lF	60	mA
LED Power Dissipation @ T <sub>A</sub> = 25°C with Negligible Power in Output Detector	PD	150	mW
Derate above 25°C		1.41	mW/°C

## **OUTPUT DETECTOR**

Collector–Emitter Voltage	VCEO	25	Volts
Emitter–Base Voltage	VEBO	7	Volts
Collector–Base Voltage	Vсво	30	Volts
Collector Current — Continuous	IC	100	mA
Detector Power Dissipation @ T <sub>A</sub> = 25°C with Negligible Power in Input LED Derate above 25°C	PD	150 1.76	mW mW/°C

#### TOTAL DEVICE

Isolation Surge Voltage(1) (Peak ac Voltage, 60 Hz, 1 sec Duration)	VISO	7500	Vac(pk)
Total Device Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	250 2.94	mW mW/°C
Ambient Operating Temperature Range <sup>(2)</sup>	TA	-55 to +100	°C
Storage Temperature Range(2)	T <sub>stg</sub>	-55 to +150	°C
Soldering Temperature (10 sec, 1/16" from case)	TL	260	°C

- 1. Isolation surge voltage is an internal device dielectric breakdown rating. For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.
- 2. Refer to Quality and Reliability Section in Opto Data Book for information on test conditions.

Preferred devices are Motorola recommended choices for future use and best overall value.

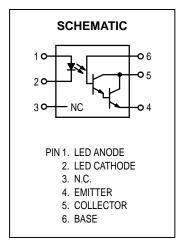
GlobalOptoisolator is a trademark of Motorola, Inc.

# H11B1\* [CTR = 500% Min]

H11B3
[CTR = 100% Min]

\*Motorola Preferred Device







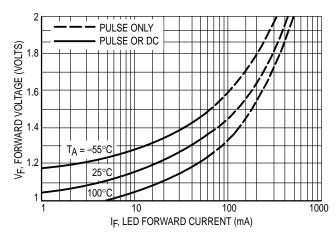
# H11B1 H11B3

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)(1)

Characteristic	Symbol	Min	<b>Typ</b> (1)	Max	Unit
INPUT LED					
Forward Voltage (I <sub>F</sub> = 10 mA) H11B1	VF	_	1.15	1.5	Volts
Forward Voltage (I <sub>F</sub> = 50 mA) H11B3	VF	_	1.34	1.5	Volts
Reverse Leakage Current (V <sub>R</sub> = 3 V)	IR	_	_	10	μΑ
Capacitance (V = 0 V, f = 1 MHz)	CJ	_	18	_	pF
OUTPUT DETECTOR					
Collector–Emitter Dark Current (V <sub>CE</sub> = 10 V)	ICEO	_	5	100	nA
Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 10 mA)	V(BR)CEO	25	80	_	Volts
Collector–Base Breakdown Voltage (I <sub>C</sub> = 100 μA)	V(BR)CBO	30	100	_	Volts
Emitter–Collector Breakdown Voltage (I <sub>E</sub> = 100 μA)	V(BR)ECO	7	_	_	Volts
DC Current Gain (I <sub>C</sub> = 5 mA, V <sub>CE</sub> = 5 V) (Typical Value)	hFE	_	16K	_	_
Collector–Emitter Capacitance (f = 1 MHz, V <sub>CE</sub> = 5 V)	C <sub>CE</sub>	_	4.9	_	pF
Collector–Base Capacitance (f = 1 MHz, V <sub>CB</sub> = 5 V)	ССВ	_	6.3	_	pF
Emitter-Base Capacitance (f = 1 MHz, V <sub>EB</sub> = 5 V)	C <sub>EB</sub>	_	3.8	_	pF
COUPLED					•
Output Collector Current (I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 5 V) H11B1 H11B3	I <sub>C</sub> (CTR) <sup>(2)</sup>	5 (500) 1 (100)	_ _	_ _	mA (%)
Collector–Emitter Saturation Voltage (I <sub>C</sub> = 1 mA, I <sub>F</sub> = 1 mA)	V <sub>CE(sat)</sub>	_	0.7	1	Volts
Turn–On Time (I <sub>F</sub> = 5 mA, $V_{CC}$ = 10 V, $R_L$ = 100 $\Omega$ ) <sup>(3)</sup>	ton	_	3.5	_	μs
Turn–Off Time (I <sub>F</sub> = 5 mA, $V_{CC}$ = 10 V, $R_L$ = 100 $\Omega$ ) <sup>(3)</sup>	t <sub>off</sub>	_	95	_	μs
Rise Time (I <sub>F</sub> = 5 mA, $V_{CC}$ = 10 V, $R_L$ = 100 $\Omega$ ) <sup>(3)</sup>	t <sub>r</sub>	_	1	_	μs
Fall Time (I <sub>F</sub> = 5 mA, $V_{CC}$ = 10 V, $R_L$ = 100 $\Omega$ ) <sup>(3)</sup>	t <sub>f</sub>	_	2	_	μs
Isolation Voltage (f = 60 Hz, t = 1 sec) <sup>(4)</sup>	VISO	7500	_	_	Vac(pk)
Isolation Resistance (V = 500 V)(4)	R <sub>ISO</sub>	10 <sup>11</sup>	_	_	Ω
Isolation Capacitance (V = 0 V, f = 1 MHz)(4)	C <sub>ISO</sub>	_	0.2	_	pF

- 1. Always design to the specified minimum/maximum electrical limits (where applicable).
- 2. Current Transfer Ratio (CTR) = I<sub>C</sub>/I<sub>F</sub> x 100%.
- 3. For test circuit setup and waveforms, refer to Figure 11.
- 4. For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.

## **TYPICAL CHARACTERISTICS**





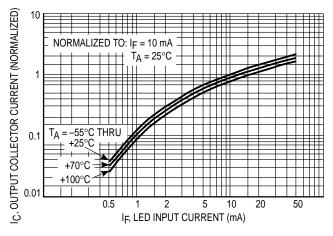


Figure 2. Output Current versus Input Current

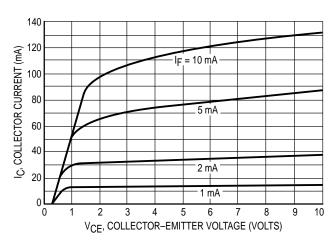


Figure 3. Collector Current versus Collector–Emitter Voltage

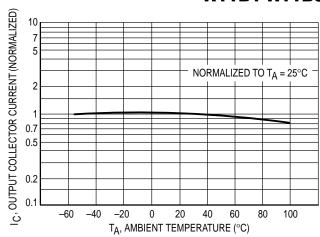


Figure 4. Output Current versus Ambient Temperature

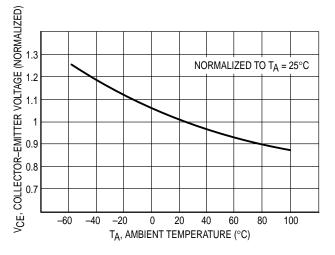


Figure 5. Collector–Emitter Voltage versus Ambient Temperature

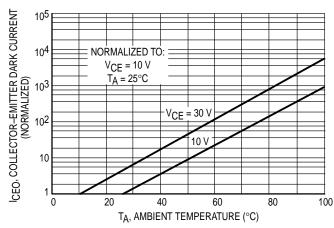


Figure 6. Collector–Emitter Dark Current versus
Ambient Temperature

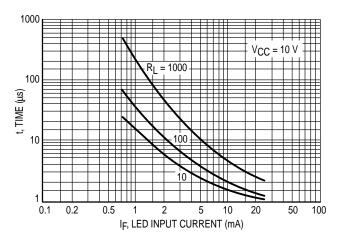


Figure 7. Turn-On Switching Times (Typical Values)

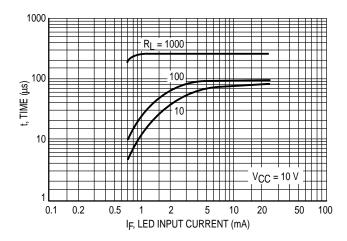
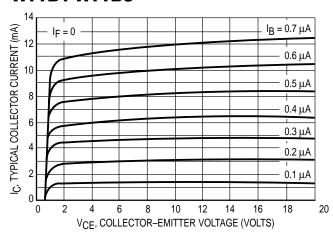


Figure 8. Turn-Off Switching Times (Typical Values)

#### H11B1 H11B3



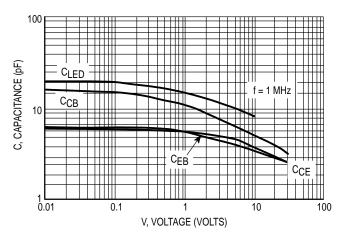


Figure 9. DC Current Gain (Detector Only)

Figure 10. Capacitance versus Voltage

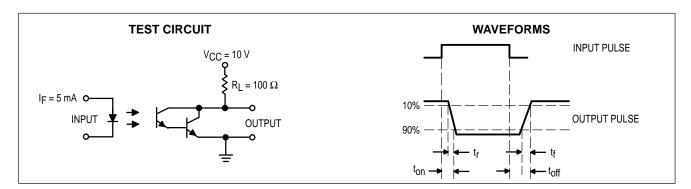
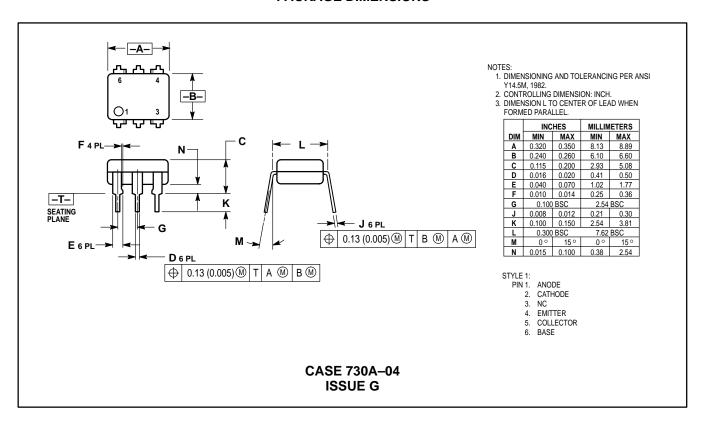
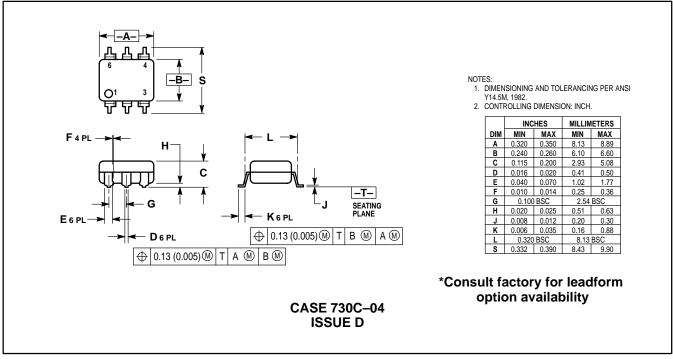


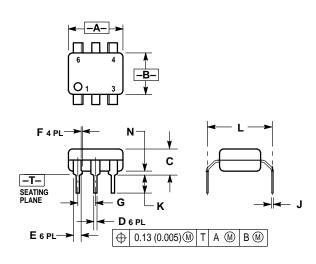
Figure 11. Switching Time Test Circuit and Waveforms

#### PACKAGE DIMENSIONS





#### H11B1 H11B3



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
   DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.

	INCHES		MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.320	0.350	8.13	8.89	
В	0.240	0.260	6.10	6.60	
С	0.115	0.200	2.93	5.08	
D	0.016	0.020	0.41	0.50	
Е	0.040	0.070	1.02	1.77	
F	0.010	0.014	0.25	0.36	
G	0.100	0.100 BSC		BSC	
7	0.008	0.012	0.21	0.30	
K	0.100	0.150	2.54	3.81	
L	0.400	0.425	10.16	10.80	
N	0.015	0.040	0.38	1.02	

\*Consult factory for leadform option availability

**CASE 730D-05 ISSUE D** 

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How to reach us:

USA/EUROPE: Motorola Literature Distribution: P.O. Box 20912; Phoenix, Arizona 85036. 1-800-441-2447

MFAX: RMFAX0@email.sps.mot.com - TOUCHTONE (602) 244-6609 INTERNET: http://Design-NET.com

JAPAN: Nippon Motorola Ltd.; Tatsumi-SPD-JLDC, Toshikatsu Otsuki, 6F Seibu-Butsuryu-Center, 3-14-2 Tatsumi Koto-Ku, Tokyo 135, Japan. 03-3521-8315

HONG KONG: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298





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